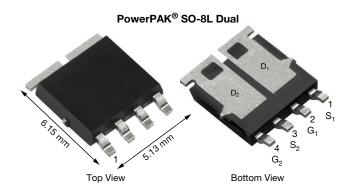


Vishay Siliconix

Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.008			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.011			
I _D (A) per leg	30			
Configuration	Dual			

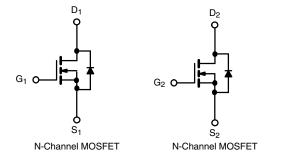
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJB40EP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATING	GS (T _C = 25 °C, unless	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40	V	
Gate-source voltage		V _{GS}	V _{GS} ± 20		
Continuous drain current	T _C = 25 °C ^a	1	30		
	T _C = 125 °C	I _D	29	1	
Continuous source current (diode conduction) ^a		I _S	30	Α	
Pulsed drain current b		I _{DM}	80		
Single pulse avalanche current		I _{AS}	22		
Single pulse avalanche energy L = 0.1 mH		E _{AS}	24	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	34	W	
	T _C = 125 °C	P_{D}	11		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) d		-	260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction to ambient	PCB mount c	R_{thJA}	85	°C/W
Junction to case (drain)		R_{thJC}	4.3	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.2	1.8	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μΑ
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	20	-	-	Α
		V _{GS} = 10 V	I _D = 8 A	-	0.0063	0.0080	
Dusin course or state unsistence 2	Б	V _{GS} = 10 V	I _D = 8 A, T _J = 125 °C	-	-	0.0117	Ω
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 8 A, T _J = 175 °C	-	-	0.0138	
		V _{GS} = 4.5 V	I _D = 5 A	-	0.0083	0.0110	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 8 A	-	48	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	1415	1900	
Output capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	935	1300	pF
Reverse transfer capacitance	C _{rss}			-	45	65	
Total gate charge ^c	Q_g			-	20	35	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 5 \text{ A}$	-	4.3	-	nC
Gate-drain charge ^c	Q _{gd}	1		-	2.5	-	
Gate resistance	R_g		f = 1 MHz	0.30	0.74	1.20	Ω
Turn-on delay time ^c	t _{d(on)}			-	7	15	
Rise time ^c	t _r	V_{DD}	= 20 V, $R_L = 4 \Omega$	-	20	35	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 5 \text{ A}, $	$I_D \cong 5 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		18	35	ns
Fall time ^c	t _f	1		-	15	25	
Source-Drain Diode Ratings and Charac	teristics ^b						
Pulsed current ^a	I _{SM}			-	-	80	Α
Forward voltage	V _{SD}	l _F =	= 8 A, V _{GS} = 0 V	-	0.803	1.200	V
Body diode reverse recovery time	t _{rr}			-	50	100	ns
Body diode reverse recovery charge	Q _{rr}] , ,	۸ ماناطه ۱۰۰ ۸ /··-	-	60	120	nC
Reverse recovery fall time	ta	I _F = 8	A, di/dt = 100 A/μs	-	27	-	
Reverse recovery rise time	t _b	1		-	23	-	ns
Body diode peak reverse recoverycurrent	I _{RM(REC)}			-	-2.3	-	Α

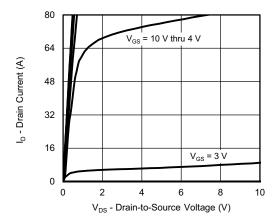
Notes

- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

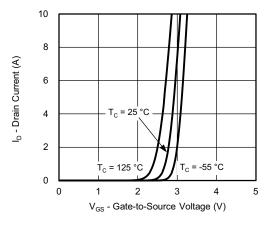
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



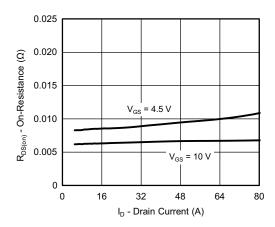
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



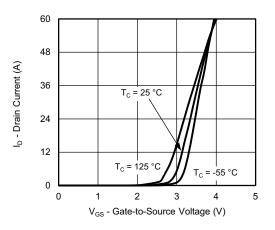
Output Characteristics



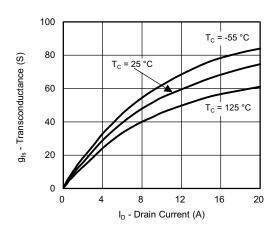
Transfer Characteristics



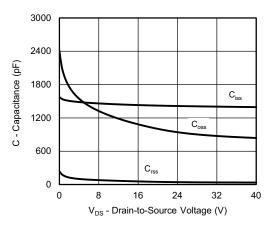
On-Resistance vs. Drain Current



Transfer Characteristics



Transconductance

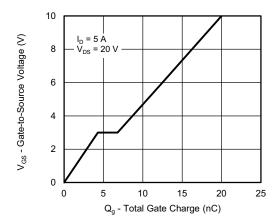


Capacitance

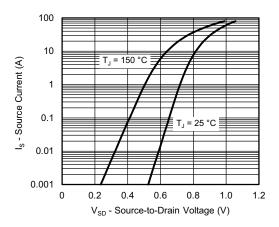
For technical questions, contact: automostechsu



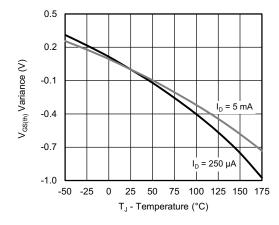
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



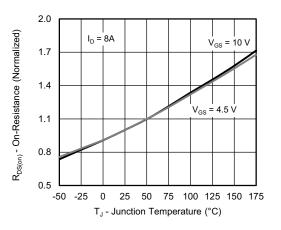
Gate Charge



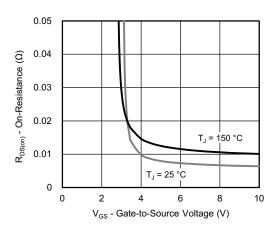
Source Drain Diode Forward Voltage



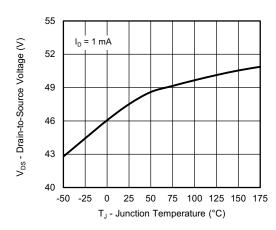
Threshold Voltage



On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

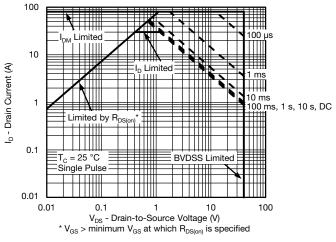


Drain Source Breakdown vs. Junction Temperature

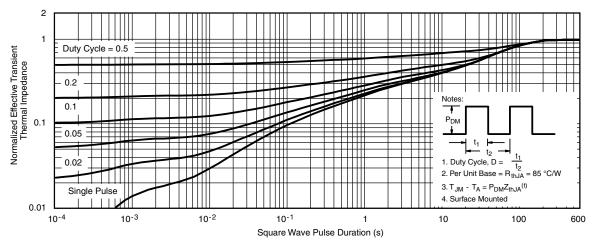
For technical questions, contact: automostechsu



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



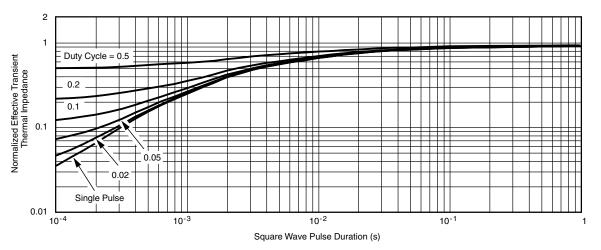
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68550.



PowerPAK® SO-8L Case Outline 2





www.vishay.com

Vishay Siliconix

DIM	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
E3	6.05	6.22	6.40	0.238	0.245	0.252	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W	0.23		0.009				
W1		0.41		0.016			
W2	2.82		0.111				
W3	2.96		0.117				
θ	0°	-	10°	0°	-	10°	

DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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Vishay

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